Philips Components-Signetics

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Status	Product Specification			
Memory Products				

DESCRIPTION

The 82S147 and 82S147A are fieldprogrammable, which means that custom patterns are immediately available by following the Signetics Generic I fusing procedure. The standard devices are supplied with all outputs at locical Low. Outputs are programmed to a logic High level at any specified address by fusing the Ni-Cr link matrix.

The 82S147 and 82S147A include on-chip decoding and one Chip Enable input for ease of memory expansion, and feature 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82S147 and 82S147A devices are also processed to military requirements for operation over the military temperature range. For specifications and ordering information consult the Signetics Military Data Handbook.

BLOCK DIAGRAM

82S147 / 82S147A 4K-bit TTL bipolar PROM

FEATURES

Address access time:

- N82S147: 60ns max
- N82S147A: 45ns max
- Power dissipation: 625mW/bit typ
- Input loading: -100µA max
- One Chip Enable input
- On-chip address decoding
- No separate fusing pins
- Fully TTL compatible
- Outputs: 3-State
- Unprogrammed outputs are Low level

APPLICATIONS

- Prototyping/volume production
- Sequential controllers
- Microprogramming
- Hardwired algorithms
- Control store
- Random logic
- Code conversion

PIN CONFIGURATIONS





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Product Specification

4K-bit TTL bipolar PROM (512 \times 8)

82S147 / 82S147A

ORDERING INFORMATION

DESCRIPTION	ORDER CODE				
20-Pin Plastic Dual-In-Line 300mil-wide	N82S147 N, N82S147A N				
20-Pin Plastic Leaded Chip Carrier 350mil-square	N82S147 A, N82S147A A				

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT	
Vcc	Supply voltage	+7.0	V _{DC}	
V _{IN}	Input voltage	+5.5	VDC	
Vo	Output voltage Off-State	+5.5	VDC	
Tamb	Operating temperature range	0 to +75	Ŷ	
T _{stg}	Storage temperature range	-65 to +150	°C	

DC ELECTRICAL CHARACTERISTICS $0^{\circ}C \leq T_{amb} \leq +75^{\circ}C, 4.75V \leq V_{CC} \leq 5.25V$

SYMBOL		TEST CONDITIONS ^{1,2}		LIMITS			
	PARAMETER		Min	Тур ³	Max	UNIT	
Input volt	age						
V _{IL}	Low				0.8	v	
VIH	High		2.0			v	
VIC	Clamp	l _{IN} = -12mA		-0.8	-1.2	V	
Output vo	bitage						
		CE = Low		T			
VOL	Low	I _{OUT} = 9.6mA		1	0.45	v	
VoH	High	l _{OUT} = -2mA	2.4			v	
Input cur	rent						
	Low	V _{IN} = 0.45V		1	-100	μΑ	
l _{iH}	High	$V_{IN} = 5.5V$			40	μΑ	
Output c	urrent						
loz	Hi-Z state	CE = High, V _{OUT} = 5.5V		I	40	μΑ	
		CE = High, V _{OUT} = 0.5V			-40] μΑ	
los	Short circuit ⁴	$\overline{CE} = Low, V_{OUT} = 0V$	-15		-70	mA	
Supply c	urrent ⁵						
lcc		V _{CC} ≈ 5.25V		125	155	mA	
Capacita	nce						
	[CE = High, V _{CC} = 5.0V			1	I	
CIN	Input	V _{IN} = 2.0V		5		p₽	
COUT	Output	V _{OUT} = 2.0V	1	8		рF	

NOTES:

1. All voltages with respect to network ground. 2. Positive current is defined as into the terminal referenced. 3. Typical values are at $V_{CC} = 5V$, $T_{amb} = +25^{\circ}C$. 4. Duration of the short circuit should not exceed 1 second.

5. Measured with all inputs grounded and all outputs open.

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4K-bit TTL bipolar PROM (512 × 8)

82S147 / 82S147A

AC ELECTRICAL CHARACTERISTICS

 $R_1 = 270\Omega$, $R_2 = 600\Omega$, $C_L = 30pF$, $0^{\circ}C \le T_{amb} \le +75^{\circ}C$, $4.75V \le V_{CC} \le 5.25V$

SYMBOL	PARAMETER	то	FROM	N82S147		N82S147A				
				Min	Typ1	Max	Min	Typ ¹	Max	UNIT
Access tim	18 ²									
taa		Output	Address	T	45	60		40	45	ns
t CE		Output	Chip Enable		20	35		20	30	ns
Disable tin	ne ³									
tcD		Output	Chip Disable	1	20	35		20	30	ns
DTEC.					-	•	·	•	••	

1. Typical values are at V_{CC} = 5V, T_{amb} = +25°C. 2. Tested at an address cycle time of 1 μ s. 3. Measured at a delta of 0.5V from Logic Level with R₁ = 750 Ω , R₂ = 750 Ω , C_L = 5pF.

TEST LOAD CIRCUIT



VOLTAGE WAVEFORMS



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